B10 RF Relays



Ball Grid Array Relays

Coto's Ball Grid Array (BGA) construction offers a breakthrough in reed relay performance. This patented technology¹ allows for shorter RF paths in a controlled 50 Ω environment to minimize signal attentuation. The designer is now able to switch or pass signals with wider bandwidth and faster rise time than alternative technologies. This is particularly important in Mixed Signal IC testers. BGA packaging allows relays to be integrated easily on boards designed for surface mount processing.

Series Features

- BGA Surface Mount
- Ability to pass GHz signals
- Rise time $< 40 \rho Sec$
- 50 Ω Characteristic Impedance
- Low Capacitance
- Patented Design¹

Applications

- IC Testers
- In-Line Relay Testers
- Memory Testers
- ♦ Mixed Signal Testers
- High Bandpass Applications

Dimensions in Inches (Millimeters)









Notes:

¹ Protected by one or more of the following US Patents: 6025768, 6052045, 6294971, 6683518, RE38381 and other foreign patents.

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				B10		
Test Parameters		Conditions ^{1,2}	Min	Тур	Max	Units
Coil Resistance			49.5	55.0	60.5	Ω
Nominal Voltage		3.3V Coil		5.0	4.0	Volts DC
Must Operate Voltage					2.4	Volts DC
Must Release Voltage			0.4			Volts DC
Coil Resistance			135.0	150.0	165.0	Ω
Nominal Voltage		5V Coil		5.0	6.0	Volts DC
Must Operate Voltage					3.8	Volts DC
Must Release Voltage			0.4			Volts DC
Switching Voltage		Max DC/Peak AC			125	Volts
Switching Current					0.25	Amps
Carry Current (Continuous)		Switch and Shield			0.5	Amps
Contact Rating (Resistive Load)		Resistive Load			3.0	Watts
Life Expectancy Signal S	witching ³	1VDC / 10mA		1000		$x 10^{6} \text{ Ops}$
Resistive	e Load ³	12VDC / 10mA		1		$x 10^{6} Ops$
Other L	oad Conditions ³	Consult Factory				
Static Contact Resistance (initial)		0.05VDC / 10mA			0.125	Ω
Dynamic Contact Resistance (initial)		0.5V / 50mA 100 Hz, 1.5 mSec			0.150	Ω
Insulation Res All Isola	ted Pins	100VDC	10 10	10^{12}		Ω
Capacitance Across G	Contacts	Shield Guarding		0.2		pF
Capacitance Open C	ontact to Coil	Shield Guarding		0.5		pF
Capacitance Closed	Contact to Coil	Shield Guarding		1		pF
Across (Contacts	$100\mu\mathrm{A}$	150			V (DC/Pk AC)
Dielectric Contact	to Coil	$100\mu\mathrm{A}$	1500			V (DC/Pk AC)
Strength Contact	to Shield	$100\mu\mathrm{A}$	1500			V (DC/Pk AC)
Operate Time (includin	ng bounce)	Nominal Voltage coil drive @ 30 Hz,		100	200	μ Sec
Release Time (Si diod	e damped)	square wave		30	50	μSec
RF Insertion Loss ⁴		-3 dB roll-off frequency	10.0			GHz
Signal Rise Time (10% - 90%)		Corrected for measurement			40	pSec
		system response time				

NOTES:

All parameters specified per EIA/NARM standards		ENVIRONMENTAL RATINGS:		
for dry reed relays, # RS-421 and RS-436, if a		Storage Temperature: -35°C to +100°C.		
suitable parametric standard exists.		Operating Temperature: -20°C to +85°C.		
Unless otherwise noted, all parameters are specified		Vibration: sinusoidal vibration with an an		
at 25°C and 40% RH.		10G over a 10Hz to 2000Hz frequency ra		
Life expectancies based on characteristic life		not cause a closed channel activated at		
(63.2% failure) calculated from the 2-parameter		coil voltage to open, not an open channe		
Weibull distribution. Contact resistance $>2.0\Omega$		Max Soldering Temperature: 438°F(226°C		
defines end of life.		1 minute dwell time. Temperature measu		
Frequency at which the difference between output		relay ball termination.		
and input signal amplitude exceeds -3dB. (Direct		Moisture sensitive component. Handle a		
wired using 500 coaxial cable)		I-STD-020B level 5a		

GS:

C to $+85^{\circ}$ C. n with an amplitude of requency range shall ctivated at the nominal open channel to close. 438°F(226°C) max for ature measured at a t. Handle as